	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	846	deposit\$3 with BSG	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 13:07			
2	BRS	L2	251	1 same (gate or fet or transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 11:57			
3	BRS	L3	100	2 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:52			
4	BRS	L5	7	4 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:22			
5	BRS	L4	101	(k or "dielectric constant") with BSG	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:52			
6	BRS	L6	94	Constant / With BOG		2004/12/03 14:03			
7	BRS	L7	7	6 and @pd<="20000320"	CPULIPUL I	2004/12/03 13:12			
8	BRS	L8	129	("low k" or "dielectric constant") same BSG	PPC), JPC), J	2004/12/03 14:21			

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
9	BRS	L9	122	8 not 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03			
10	BRS	L10	35	8 not 6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:04			
11	BRS	L11	137	("low k" or "dielectric constant") same (BSG or "boron silicate glass")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:36			
12	BRS	L13	14	12 not 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:22			
13	BRS	L12	21	11 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:37			
14	BRS	L14	11403	("low k" or "dielectric constant") with "3"		2004/12/03 14:36			
15	BRS	L16	0	15 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:37			
16	BRS I	_15	8	(("low k" or "dielectric constant") with "3") same (BSG or "boron silicate glass")		2004/12/03 14:42			

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
17	BRS	L17	8454	("low dielectric constant") and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 14:56			
18	BRS	L18	11	("low k dielectric constant") and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:33			4
19	BRS	L19	5735	(("low k" or "dielectric constant") with "3") and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:42			
20	BRS	L20	305	19 and "428"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:17			
21	BRS	L21	206	19 and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:44		·	
22	BRS	L22	300	20 not 21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:17			
23	BRS	L23	53	(("low k" or "dielectric constant") same damascene) and @pd<="""20000320"""	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 16:10			
24	BRS	L24	9038	( "dielectric constant") with ("SiO.sub.2" or "silicon dioxide" or "silicon oxide")	IEPO, IPO, I	2004/12/03 15:43			

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
25	BRS	L25	1795	24 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:45			
26	BRS	L26	579	25 and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:47			
27	BRS	L27	24	25 and "438"/\$.ccls. and (BSG or "boron silicate glass")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 15:49			
28	BRS	L28	23317535	(("low k" or "dielectric constant" or "low dielectric") with (BSG OR "BORON SILICATE GLASS")) @pd<="""20000320"""	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 16:17			
29	BRS	L29	23317535	SILICATE GLASS"))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 16:18			
30	BRS	L30	9	with (BSG OR "BORON SILICATE GLASS")) AND		2004/12/03 17:42			
31	BRS	L31		(introduc\$3 or implant\$3 or doping) with (impurit\$3 or dopant)	FPU JPU I	2004/12/03 17:46			
32	BRS I	_32	7515	31 and @pd<="20000320"	PP(), 1P(), 1	2004/12/03 17:47		-	

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
33	BRS	L33	12127	(oxide or "silicon oxide") with (introduc\$3 or implant\$3 or doping) with (impurit\$3 or boron)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03			
34	BRS	L34	7724	33 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:50			
35	BRS	L35	3543	34 and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:50			
36	BRS	L36	2947	(oxide or "silicon oxide") with (introduc\$3) with (impurit\$3 or boron)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:52			
37	BRS	L37	1922		US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:53			
38	BRS	L38	708		US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:53			
39	BRS	L39	700	(oxide or "silicon oxide") with (introduc\$3) with (boron)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 17:52			
40	BRS	_40	448	39 and @pd<="20000320"	FPOT IPOT I	2004/12/03 18:55			

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
41	BRS	L41	119	40 and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 18:56			
42	BRS	L42	74	((methyl) with (silane) with (peroxide or "H.sub.2O.sub.2")) and (dop\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 19:08			
43	BRS	L44	1	43 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 18:44			
44	BRS	L45	1	"5879574".PN.	USPAT; USOCR	2004/12/03 18:46			
45	BRS	L46	1	"5872065".PN.	USPAT; USOCR	2004/12/03 18:51			
46	BRS	L47	1	"5716890".PN.	USPAT; USOCR	2004/12/03 18:52			
47	BRS	L48	1	44 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 18:56			
48	BRS	L49	1	44 and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 18:56			-
49	BRS	L50	1	43 and @pd<="20000320"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03 18:56			
50	BRS	L43	51	((methyl) with (silane) with (peroxide or "H.sub.2O.sub.2")) same (dop\$3)	HEDIT IDO	2004/12/03 19:09			

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
51	BRS	L51	23	42 not 43	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03			
52	BRS	L52	5	"6395647"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/12/03			